Technical Data Sheet



DPDT Ramses SMA 3GHz Latching Indicators 28Vdc TTL Diodes Pins

Terminals with bracket

PAGE 1/2 ISSUE 21.01.15 SERIE : DPDT PART NUMBER : R577343100

RF CHARACTERISTICS

Frequency range : 0 - 3 GHz Impedance : 50 Ohms

Frequency (GHz)	DC - 3
VSWR max	1.20
Insertion loss max	0.20 dB
Isolation min	80 dB
Average power (*)	240 W

ELECTRICAL CHARACTERISTICS

Actuator : LATCHING
Nominal current ** : 125 mA

Actuator voltage (Vcc) : 28V (24 to 30V)

Terminals : solder pins (250°C max. / 30 sec.)

Indicator rating : 1 W / 30 V / 100 mA

TTL inputs (E) - High level : **2.2 to 5.5 V / 800μA at 5.5 V**

- Low level : 0 to 0.8 V / 20µA at 0.8 V

MECHANICAL CHARACTERISTICS

Connectors : SMA female per MIL-C 39012

Life : 2.5 million cycles

Switching Time*** : <15 ms

Construction : Splashproof

Weight : <100 g

ENVIRONMENTAL CHARACTERISTICS

Operating temperature range : -40°C to +85°C Storage temperature range : -55°C to +85°C

(* Average power at 25°C per RF Path)

(** At 25° C ±10%)

(*** Nominal voltage; 25° C)





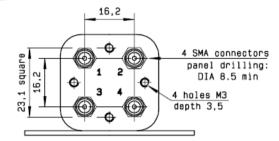


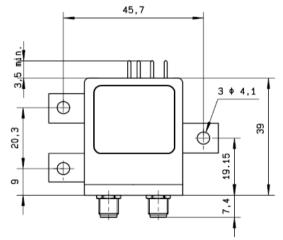
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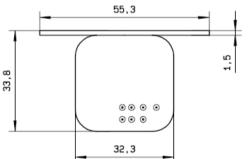
Terminals with bracket

PAGE 2/2 ISSUE 21.01.15 SERIE : DPDT PART NUMBER : R577343100

DRAWING



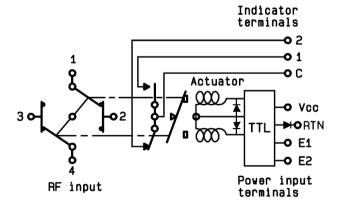




SCHEMATIC DIAGRAM

General tolerances: ±0.5 mm

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TTL input	RF Continuity	Ind.
E1=1 / E2=0	$1 \leftrightarrow 3 / 2 \leftrightarrow 4$	C.1
E1=0 / E2=1	$1 \leftrightarrow 2 / 3 \leftrightarrow 4$	C.2
E1=0 / E2=0	Memory	-
E1=1 / E2=1	Forbidden	-

LABEL

